ST600K

LOW VOLTAGE NPN POWER TRANSISTOR

PRELIMINARY DATA

Features

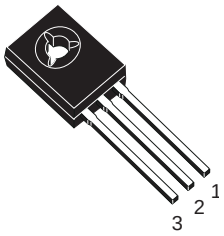
- LOW SATURATION VOLTAGE

Applications

- SCANNING VELOCITY MODULATION IN CRT DISPLAYS
- MEDIUM POWER LINEAR AND SWITCHING APPLICATIONS

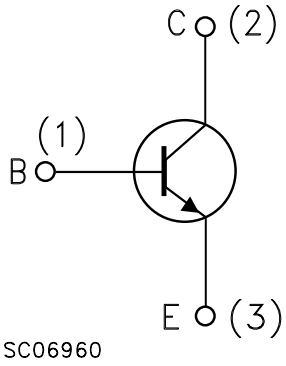
Description

The ST600K is manufactured by low voltage Epitaxial Base technology and it is housed in SOT-32 plastic package. The complementary PNP type is ST631K.



SOT-32
(TO-216)

Internal Schematic Diagram



Order Codes

Part Number	Marking	Package	Packing
ST600K	600K	SOT-32	TUBE

1 Absolute Maximum Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage (I_E = 0)	120	V
V_{CEO}	Collector-Emitter Voltage (I_B = 0)	120	V
V_{EBO}	Collector-Base Voltage (I_C = 0)	5	V
I_C	Collector Current	1	A
I_{CM}	Collector Peak Current (t_P < 5ms)	2	A
I_B	Base Current	0.5	A
I_{BM}	Base Peak Current (t_P < 5ms)	1	A
P_{TOT}	Total dissipation at T_c = 25°C	12.5	W
T_{STG}	Storage Temperature	-65 to 150	°C
T_J	Max. Operating Junction Temperature	150	°C

Table 2. Thermal Data

Symbol	Parameter		Value	Unit
$R_{thJ\text{-}case}$	Thermal Resistance Junction-Case	Max	10	°C/W
$R_{thJ\text{-}amb}$	Thermal Resistance Junction-Case	Max	100	°C/W

2 Electrical Characteristics

Table 3. Electrical Characteristics (T_{CASE} = 25°C; unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current (I_E = 0)	V_{CB} = 50V			1	µA
I_{EBO}	Emitter Cut-off Current (I_C = 0)	V_{EB} = 4V			1	µA
$V_{(BR)CBO}$ *Note: 1*	Collector-Base Breakdown Voltage (I_E = 0)	I_C = 10µA	120			V
$V_{(BR)CEO}$ *Note: 1*	Collector-Emitter Breakdown Voltage (I_C = 0)	I_E = 1 mA	120		1	V
$V_{(BR)EBO}$ *Note: 1*	Collector-Emitter Breakdown Voltage (I_B = 0)	I_C = 10 mA	120		1	V
$V_{CE(sat)}$ *Note: 1*	Collector-Emitter Saturation Voltage	I_C = 500 mA I_B = 50 mA			0.5	V
$V_{BE(sat)}$ *Note: 1*	Base-Emitter Saturation Voltage	I_C = 500 mA I_B = 50 mA			1.2	V
h_{FE} *Note: 1*	DC Current Gain	I_C = 100 mA V_{CE} = 5 V I_C = 500 mA V_{CE} = 5 V	120 50		280	
C_{CBO}	Collector-Base Capacitance (I_B = 0)	V_{CB} = 10 V f=1MHz		40		pF
 t_{on} t_{off} t_s	INDUCTIVE LOAD Turn-On Time Turn-Off Time Storage Time	I_C = 500 mA V_{CC} = 12V I_{B1} = - I_{B2} =50 mA t_p = 20µs		 100 500 800		 ns ns ns

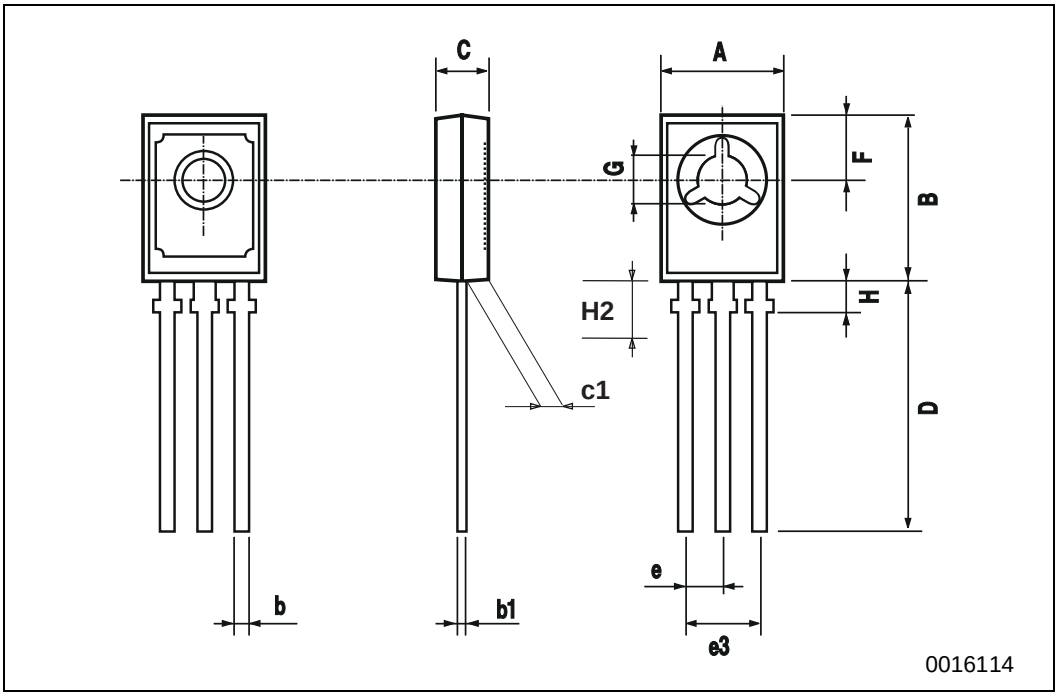
Note: 1 Pulsed duration = 300 µs, duty cycle ≤1.5%.

3 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	7.4		7.8	0.291		0.307
B	10.5		10.8	0.413		0.445
b	0.7		0.9	0.028		0.035
b1	0.49		0.75	0.019		0.030
C	2.4		2.7	0.040		0.106
c1	1.0		1.3	0.039		0.050
D	15.4		16.0	0.606		0.629
e		2.2			0.087	
e3	4.15		4.65	0.163		0.183
F		3.8			0.150	
G	3		3.2	0.118		0.126
H			2.54			0.100
H2		2.15			0.084	



4 Revision History

Date	Revision	Changes
26-Jul-2005	1	Initial release.